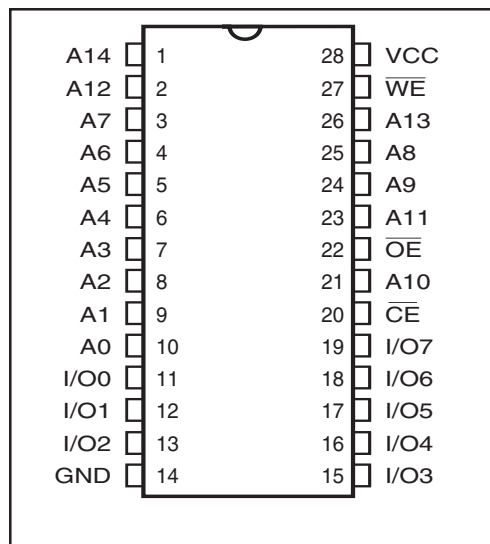


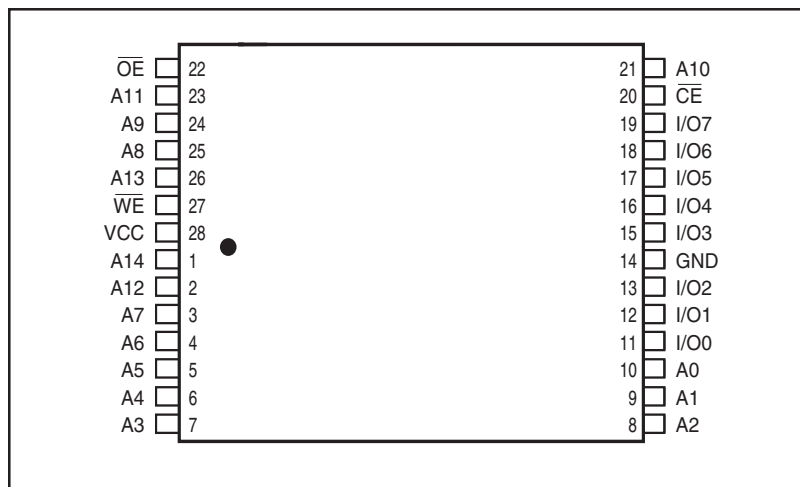
PIN CONFIGURATION

28-Pin SOJ



PIN CONFIGURATION

28-Pin TSOP



PIN DESCRIPTIONS

A0-A14	Address Inputs
$\overline{CE}$	Chip Enable Input
$\overline{OE}$	Output Enable Input
$\overline{WE}$	Write Enable Input
I/O0-I/O7	Bidirectional Ports
Vcc	Power
GND	Ground

TRUTH TABLE

Mode	$\overline{WE}$	$\overline{CE}$	$\overline{OE}$	I/O Operation	Vcc Current
Not Selected (Power-down)	X	H	X	High-Z	IsB1, IsB2
Output Disabled	H	L	H	High-Z	Icc
Read	H	L	L	DOUT	Icc
Write	L	L	X	DIN	Icc

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Parameter	Value	Unit
V _{TERM}	Terminal Voltage with Respect to GND	-0.5 to +7.0	V
T _{BIAS}	Temperature Under Bias	-55 to +125	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _T	Power Dissipation	1.5	W
I _{OUT}	DC Output Current (LOW)	20	mA

Note:

1. Stress greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

OPERATING RANGE

Range	Ambient Temperature	Speed	V _{CC}
Commercial	0°C to +70°C	-10, -12	5V ± 5%
		-15, -20	5V ± 10%
Industrial	-40°C to +85°C	-12	5V ± 5%
		-15, -20	5V ± 10%

DC ELECTRICAL CHARACTERISTICS (Over Operating Range)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V _{OH}	Output HIGH Voltage	V _{CC} = Min., I _{OH} = -4.0 mA	2.4	—	V
V _{OL}	Output LOW Voltage	V _{CC} = Min., I _{OL} = 8.0 mA	—	0.4	V
V _{IH}	Input HIGH Voltage		2.2	V _{CC} + 0.5	V
V _{IL}	Input LOW Voltage ⁽¹⁾		-0.5	0.8	V
I _{LI}	Input Leakage	GND - V _{IN} - V _{CC}	Com. -5 Ind. -10	5 10	μA
I _{LO}	Output Leakage	GND - V _{OUT} - V _{CC} , Outputs Disabled	Com. -5 Ind. -10	5 10	μA

Note:

1. V_{IL} = -3.0V for pulse width less than 10 ns.

POWER SUPPLY CHARACTERISTICS⁽¹⁾ (Over Operating Range)

Symbol	Parameter	Test Conditions		-10		-12		-15		-20		Unit
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
I _{CC}	V _{CC} Dynamic Operating Supply Current	V _{CC} = Max., $\overline{CE}$ = V _{IL} I _{OUT} = 0 mA, f = f _{MAX}	Com.	—	165	—	155	—	145	—	135	mA
			Ind.	—	—	—	165	—	155	—	145	
I _{SB1}	TTL Standby Current (TTL Inputs)	V _{CC} = Max., V _{IN} = V _{IH} or V _{IL} $\overline{CE}$ • V _{IH} , f = 0	Com.	—	25	—	25	—	25	—	25	mA
			Ind.	—	—	—	30	—	30	—	30	
I _{SB2}	CMOS Standby Current (CMOS Inputs)	V _{CC} = Max., $\overline{CE}$ • V _{CC} - 0.2V, V _{IN} • V _{CC} - 0.2V, or V _{IN} - 0.2V, f = 0	Com.	—	2	—	2	—	2	—	2	mA
			Ind.	—	—	—	10	—	10	—	10	

Note:

1. At f = f_{MAX}, address and data inputs are cycling at the maximum frequency, f = 0 means no input lines change.

CAPACITANCE^(1,2)

Symbol	Parameter	Conditions	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	8	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	10	pF

Notes:

1. Tested initially and after any design or process changes that may affect these parameters.
2. Test conditions: T_A = 25°C, f = 1 MHz, V_{CC} = 5.0V.

READ CYCLE SWITCHING CHARACTERISTICS⁽¹⁾ (Over Operating Range)

Symbol	Parameter	-10 ns		-12 ns		-15 ns		-20 ns		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t _{RC}	Read Cycle Time	10	—	12	—	15	—	20	—	ns
t _{AA}	Address Access Time	—	10	—	12	—	15	—	20	ns
t _{OHA}	Output Hold Time	2	—	2	—	2	—	2	—	ns
t _{ACE}	$\overline{\text{OE}}$ Access Time	—	10	—	12	—	15	—	20	ns
t _{DOE}	$\overline{\text{OE}}$ Access Time	—	5	—	5	—	7	—	8	ns
t _{LZOE⁽²⁾}	$\overline{\text{OE}}$ to Low-Z Output	0	—	0	—	0	—	0	—	ns
t _{HZOE⁽²⁾}	$\overline{\text{OE}}$ to High-Z Output	—	5	—	6	—	7	—	9	ns
t _{LZCE⁽²⁾}	$\overline{\text{CE}}$ to Low-Z Output	2	—	3	—	3	—	3	—	ns
t _{HZCE⁽²⁾}	$\overline{\text{CE}}$ to High-Z Output	—	5	—	7	—	8	—	9	ns
t _{PU⁽³⁾}	$\overline{\text{CE}}$ to Power-Up	0	—	0	—	0	—	0	—	ns
t _{PD⁽³⁾}	$\overline{\text{CE}}$ to Power-Down	—	10	—	12	—	15	—	18	ns

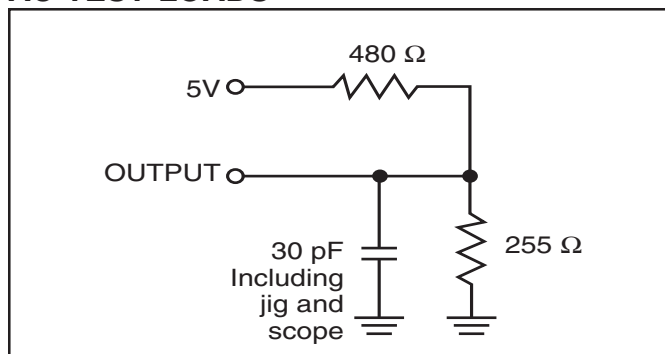
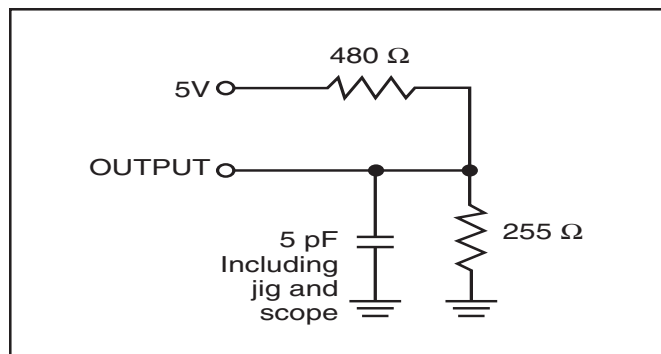
Notes:

1. Test conditions assume signal transition times of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V and output loading specified in Figure 1.
2. Tested with the load in Figure 2. Transition is measured ± 500 mV from steady-state voltage. Not 100% tested.
3. Not 100% tested.

AC TEST CONDITIONS

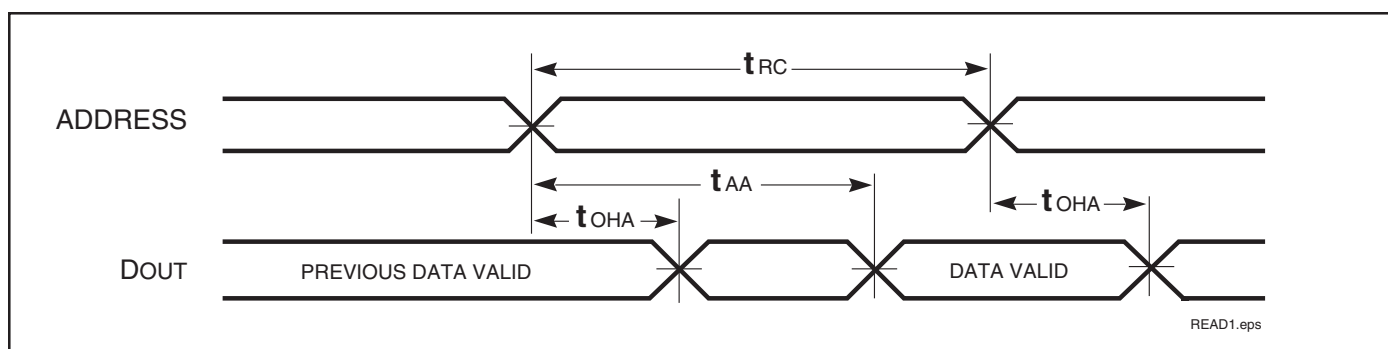
Parameter	Unit
Input Pulse Level	0V to 3.0V
Input Rise and Fall Times	3 ns
Input and Output Timing and Reference Levels	1.5V
Output Load	See Figures 1 and 2

AC TEST LOADS

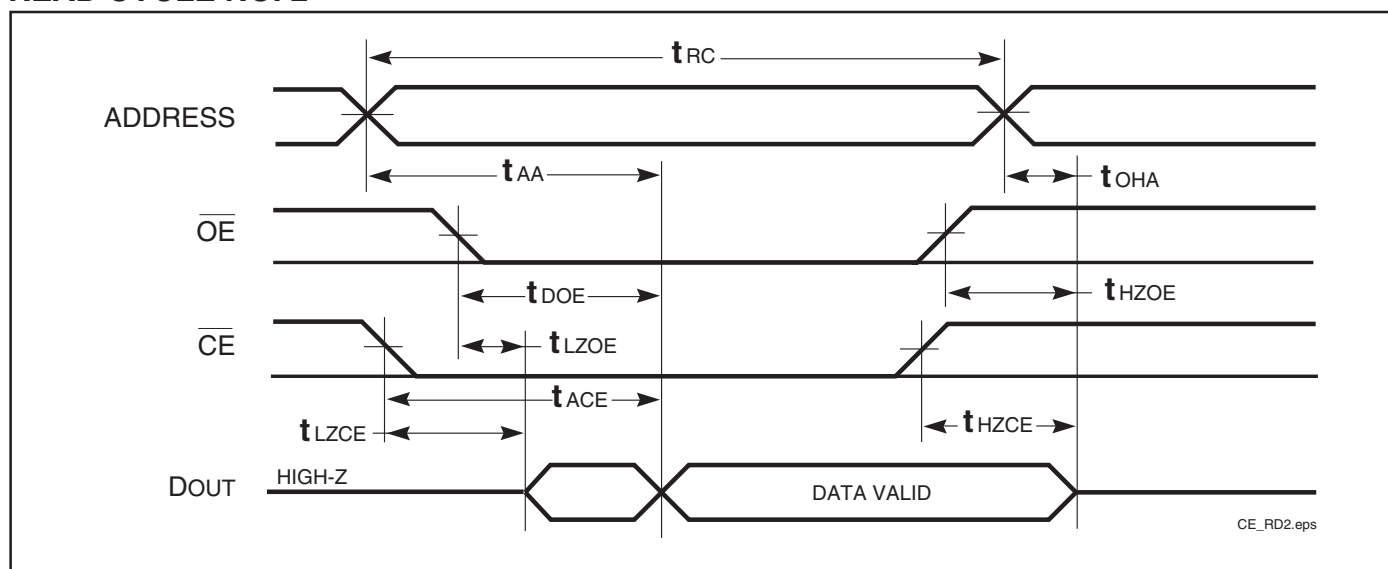

Figure 1

Figure 2

AC WAVEFORMS

READ CYCLE NO. 1^(1,2)



READ CYCLE NO. 2^(1,3)



Notes:

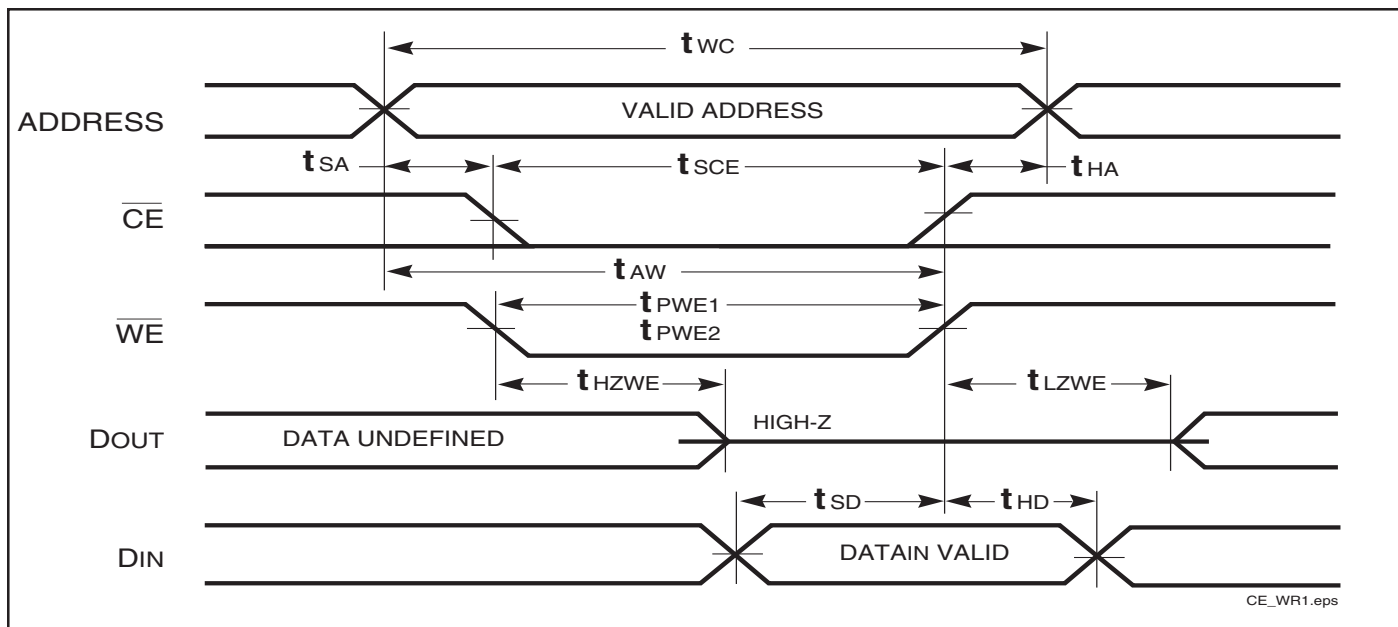
1. $\overline{WE}$ is HIGH for a Read Cycle.
2. The device is continuously selected. $\overline{OE}$, $\overline{CE} = V_{IL}$.
3. Address is valid prior to or coincident with $\overline{CE}$ LOW transitions.

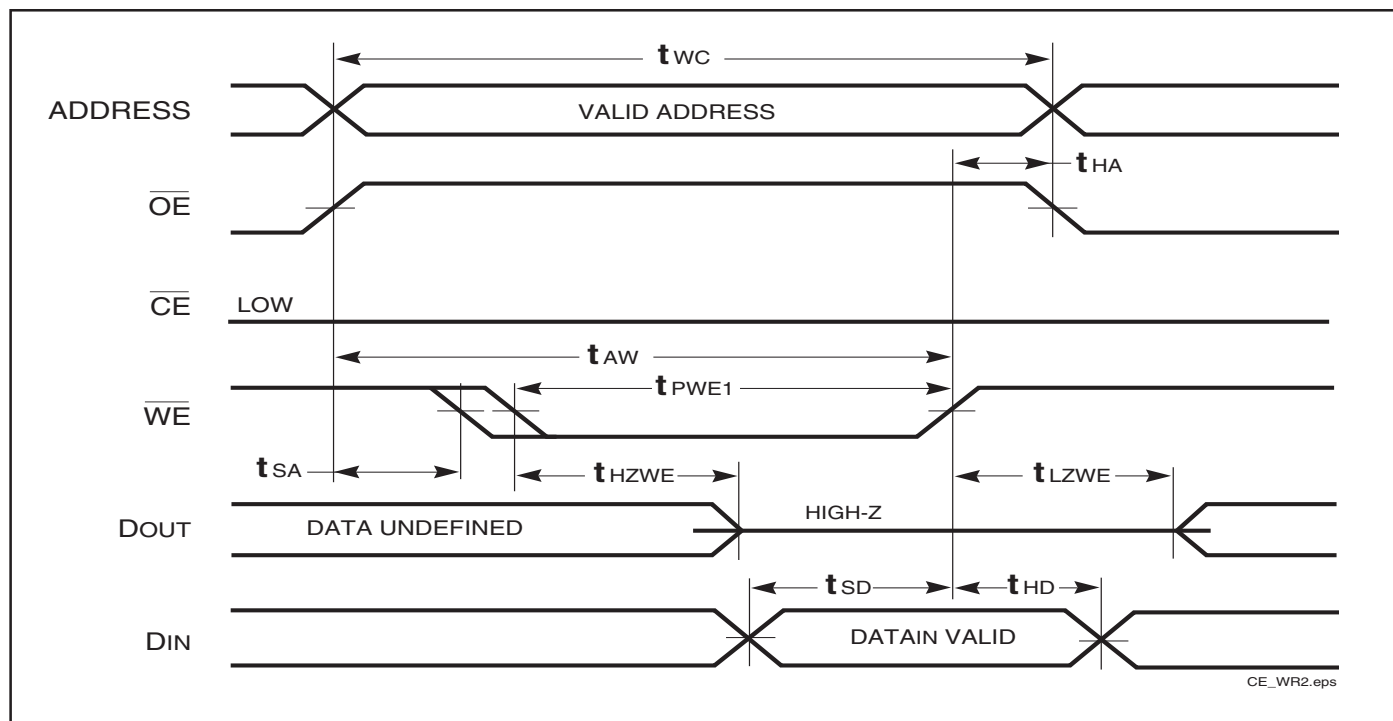
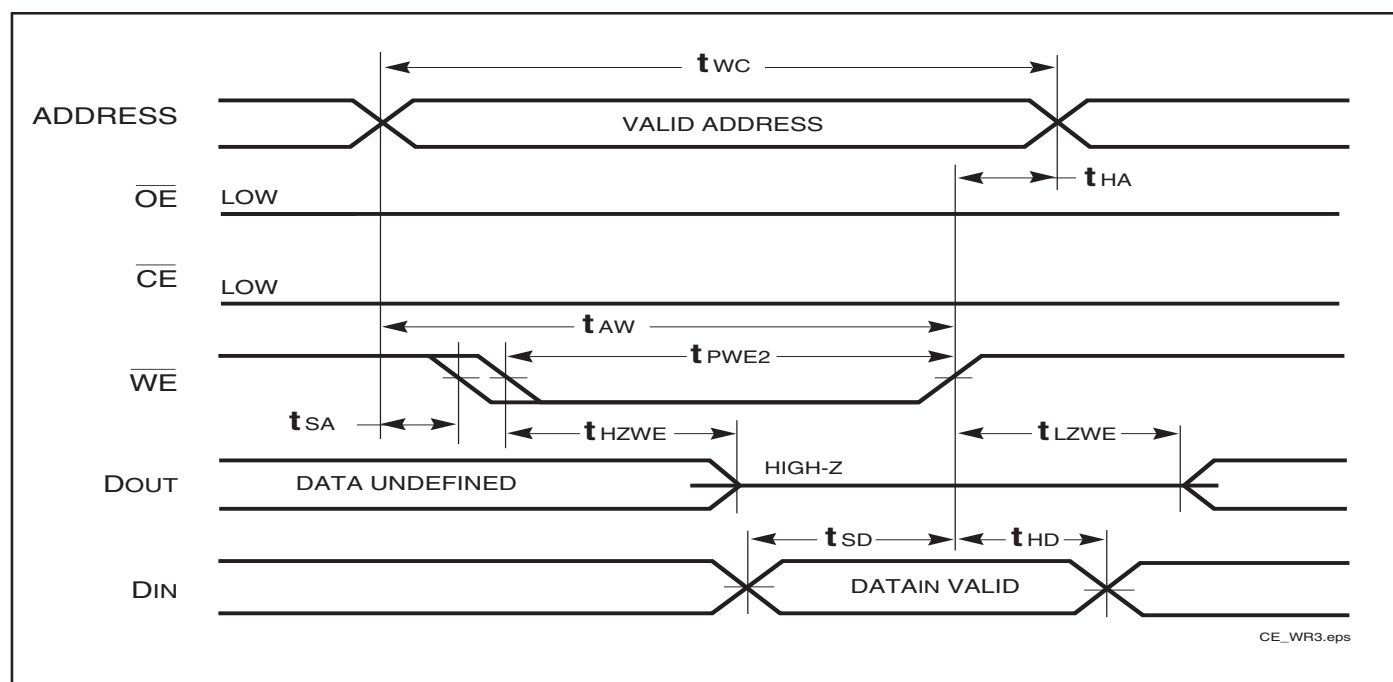
WRITE CYCLE SWITCHING CHARACTERISTICS^(1,3) (Over Operating Range)

Symbol	Parameter	-10 ns		-12 ns		-15 ns		-20 ns		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t_{WC}	Write Cycle Time	10	—	12	—	15	—	20	—	ns
t_{SCE}	$\overline{CE}$ to Write End	9	—	10	—	10	—	13	—	ns
t_{AW}	Address Setup Time to Write End	9	—	10	—	12	—	15	—	ns
t_{HA}	Address Hold from Write End	0	—	0	—	0	—	0	—	ns
t_{SA}	Address Setup Time	0	—	0	—	0	—	0	—	ns
t_{PWE1}	$\overline{WE}$ Pulse Width ($\overline{OE}$ LOW)	8	—	8	—	10	—	13	—	ns
t_{PWE2}	$\overline{WE}$ Pulse Width ($\overline{OE}$ HIGH)	6.5	—	7	—	8	—	10	—	ns
t_{SD}	Data Setup to Write End	7	—	7	—	9	—	10	—	ns
t_{HD}	Data Hold from Write End	0	—	0	—	0	—	0	—	ns
$t_{HZWE}^{(2)}$	$\overline{WE}$ LOW to High-Z Output	—	6	—	6	—	7	—	8	ns
$t_{LZWE}^{(2)}$	$\overline{WE}$ HIGH to Low-Z Output	0	—	0	—	0	—	0	—	ns

Notes:

1. Test conditions assume signal transition times of 3 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V and output loading specified in Figure 1.
2. Tested with the load in Figure 2. Transition is measured ± 500 mV from steady-state voltage. Not 100% tested.
3. The internal write time is defined by the overlap of $\overline{CE}$ LOW and $\overline{WE}$ LOW. All signals must be in valid states to initiate a Write, but any one can go inactive to terminate the Write. The Data Input Setup and Hold timing are referenced to the rising or falling edge of the signal that terminates the write.

AC WAVEFORMS
WRITE CYCLE NO. 1 ($\overline{WE}$ Controlled)^(1,2)


WRITE CYCLE NO. 2 ($\overline{OE}$ is HIGH During Write Cycle) ^(1,2)

WRITE CYCLE NO. 3 ($\overline{OE}$ is LOW During Write Cycle) ⁽¹⁾

Notes:

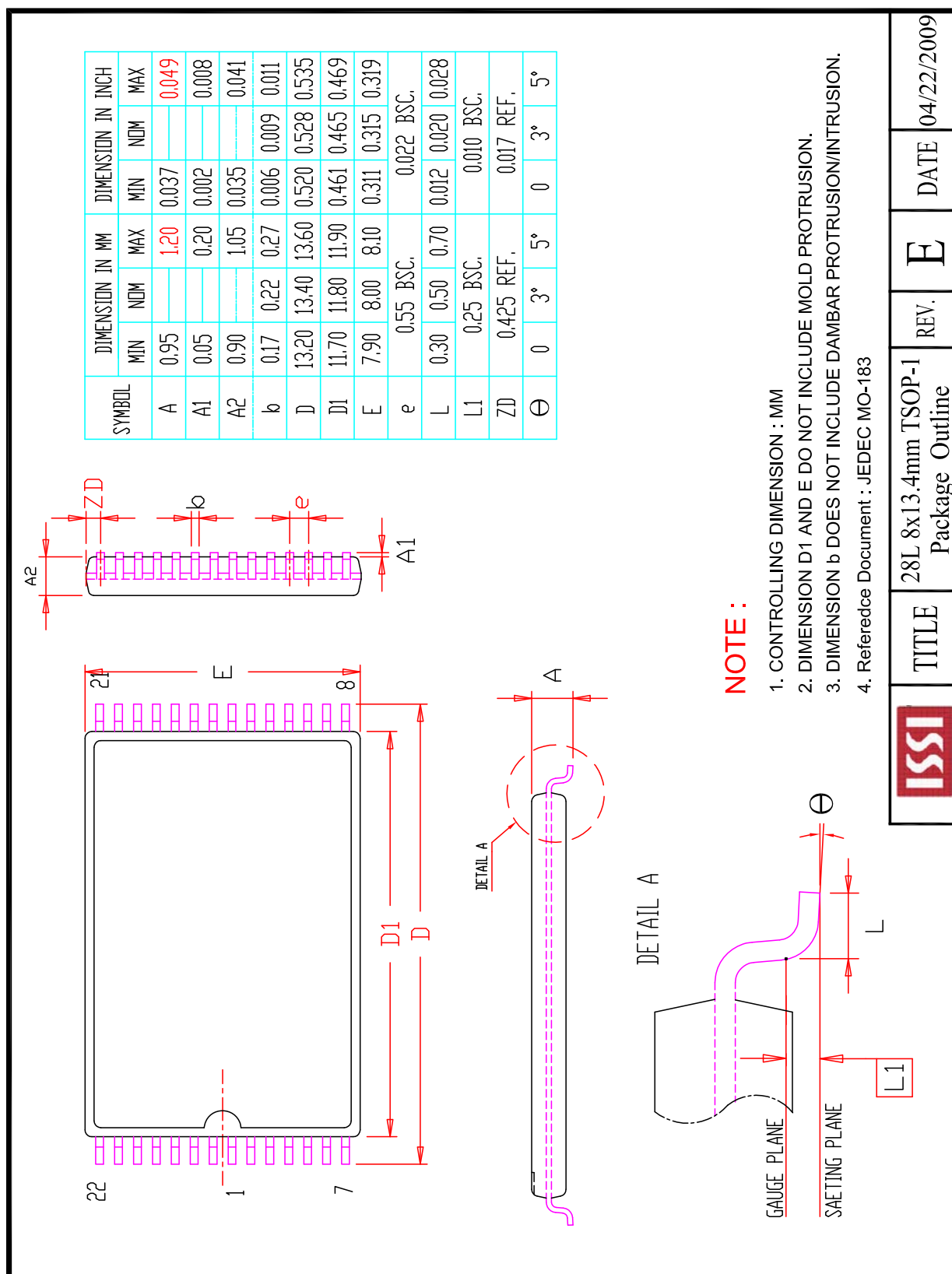
1. The internal write time is defined by the overlap of $\overline{CE}$ LOW and $\overline{WE}$ LOW. All signals must be in valid states to initiate a Write, but any one can go inactive to terminate the Write. The Data Input Setup and Hold timing are referenced to the rising or falling edge of the signal that terminates the Write.
2. I/O will assume the High-Z state if $\overline{OE} \cdot V_{IH}$.

ORDERING INFORMATION: IS61C256AH**Commercial Range: 0°C to +70°C**

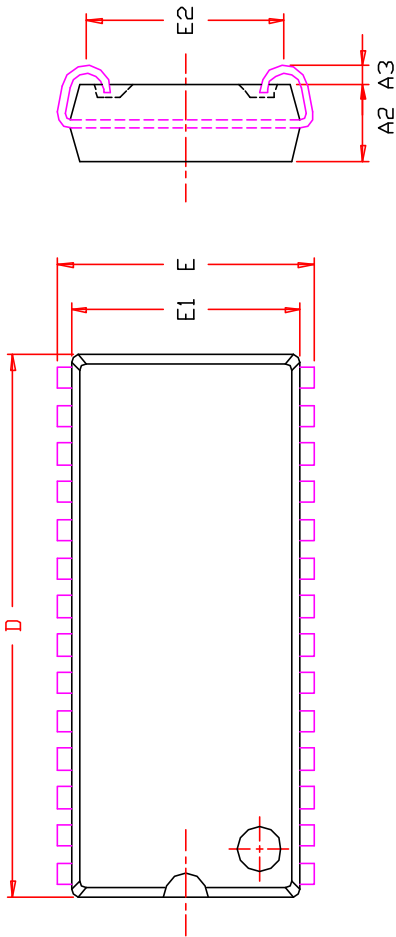
Speed (ns)	Order Part Number	Package
10	IS61C256AH-10J	300-mil Plastic SOJ
	IS61C256AH-10T	TSOP (Type 1)
12	IS61C256AH-12J	300-mil Plastic SOJ
	IS61C256AH-12JL	300-mil Plastic SOJ, Lead-free
	IS61C256AH-12T	TSOP (Type 1)
	IS61C256AH-12TL	TSOP (Type 1), Lead-free
15	IS61C256AH-15J	300-mil Plastic SOJ
	IS61C256AH-15JL	300-mil Plastic SOJ, Lead-free
	IS61C256AH-15T	TSOP (Type 1)
20	IS61C256AH-20J	300-mil Plastic SOJ
	IS61C256AH-20T	TSOP (Type 1)

ORDERING INFORMATION: IS61C256AH**Industrial Range: -40°C to +85°C**

Speed (ns)	Order Part Number	Package
12	IS61C256AH-12JI	300-mil Plastic SOJ
	IS61C256AH-12TI	TSOP (Type 1)
15	IS61C256AH-15JI	300-mil Plastic SOJ
	IS61C256AH-15TI	TSOP (Type 1)
20	IS61C256AH-20JI	300-mil Plastic SOJ
	IS61C256AH-20TI	TSOP (Type 1)

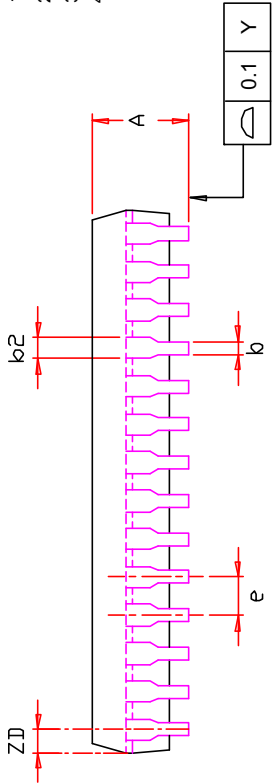


SYMBOL	DIMENSION IN MM	
	MIN.	NOM. MAX.
A	3.05	3.76
A2	2.41	2.54 2.67
A3	0.64	1.09
b	0.36	0.56
b2	0.66	0.81
D	17.70	18.54
E	8.26	8.56 8.81
E1	7.42	7.75
E2	6.22	7.29
e	1.27 BSC	
ZD	0.95 REF.	
Y	0.1	



NOTE :

- 1. Controlling dimension : mm
- 2. Dimension D1 adn E do not include mold protrusion .
- 3. Dimension b2 does not include dambar protrusion/intrusion.
- 4. Formed leads shall be planar with respect to one another within 0.1mm at the seating plane after final test.



ISSI®	TITLE	28L 300mil SOJ Package Outline	REV.	C	DATE	07/05/2006
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